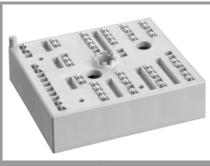
SKIIP 24ACC12T4V1



MiniSKiiP[®] 2

IGBT module

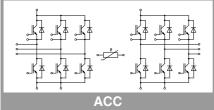
SKiiP 24ACC12T4V1

Features

- Trench 4 IGBTs
- ٠ Robust and soft freewheeling diodes in CAL technology
- · Highly reliable spring contacts for
- electrical connections • UL recognised: File no. E63532
- **Typical Applications***
- 4Q inverters

Remarks

- · Max. case temperature limited to T_C=125°C
- · Product reliability results valid for T_i≤150°C (recommended T_{j,op}=-40...+150°C)
- · Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V_{DC}≤800V
- Temperature sensor: no basic • insulation to main circuit, signal processing with reference to -DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information
- Inverter IGBT=T1-T12
- Inverse Diode=D1-D12 •



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Absolute	Maximum Rating	S				
Symbol	Conditions		Values			Unit
Inverter -	IGBT					
V _{CES}	T _j = 25 °C	= 25 °C 1200			V	
Ic	λ _{paste} =0.8 W/(mK)	T _s = 25 °C		38		Α
	T _j = 175 °C	T _s = 70 °C		31		Α
I _C	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C		43		Α
		T _s = 70 °C		35		А
I _{Cnom}			25		Α	
I _{CRM}	$I_{CRM} = 3 \times I_{Cnom}$		75			Α
V _{GES}				-20 20		V
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10		μs	
Tj			-40 175		°C	
Inverse -	Diode					
I _F	$\lambda_{paste}=0.8 \text{ W/(mK)}$ T _j = 175 °C	T _s = 25 °C		31		Α
		T _s = 70 °C		25		Α
I _F	$\lambda_{\text{paste}}=2.5 \text{ W/(mK)}$ T _s = 25 °C 34			Α		
	T _j = 175 °C	T _s = 70 °C		27		Α
I _{Fnom}			25		Α	
I _{FRM}	I _{FRM} = 2 x I _{Fnom}		50			Α
I _{FSM}	t _p = 10 ms, sin 180°, T _j = 150 °C		100			Α
Tj			-40 175		°C	
Module						
I _{t(RMS)}	T _{terminal} = 80 °C, 20	A per spring		40		Α
T _{stg}			-40 125		°C	
V _{isol}	AC sinus 50 Hz, t =	1 min	2500		V	
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
V _{CE(sat)}	I _C = 25 A	T _j = 25 °C		1.85	2.10	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.25	2.45	V

		.]	
	$du/dt = 3400 V/\mu s$	T 150.00	
	du/dt = 3400 V/μs V _{GE} = +15/-15 V L _s = 21 nH	T _j = 150 °C	
	per IGBT, $\lambda_{paste}=0.8$	3 W/(mK)	
	per IGBT, λ_{paste} =2.5	5 W/(mK)	
B	Rev 10-26022	010	

 $T_i = 25 °C$

T_j = 150 °C

 $T_i = 25 °C$

T_i = 150 °C

f = 1 MHz

f = 1 MHz

f = 1 MHz

T_i = 150 °C

T_i = 150 °C

T_i = 150 °C

T_j = 150 °C

0.80

0.70

42

62

5.8

0.1

1.43

0.12

0.09

142

0

39

32

3.2

333

91

3

1.13

0.94

5

0.90

0.80

48

66

6.5

0.3

V

V

 $m\Omega$

 $\mathsf{m}\Omega$

V

mA

nF

nF

nF

nC

Ω

ns

ns

mJ

ns

ns

mJ K/W

K/W

chiplevel

V_{GE} = 15 V

 $V_{CE} = 25 V$

 $V_{GE} = 0 V$

T_i = 25 °C

 $I_{\rm C} = 25 \, \text{A}$

V_{CC} = 600 V

 $R_{G on} = 27 \Omega$

 $R_{G off} = 27 \ \Omega$

di/dt_{on} = 780 A/µs

di/dt_{off} = 360 A/μs T_i = 150 °C

 $V_{GE} = V_{CE}, I_C = 1 \text{ mA}$

V_{GE} = - 8 V...+ 15 V

V_{GE} = 0 V, V_{CE} = 1200 V, T_i = 25 °C

chiplevel

V_{CE0}

 r_{CE}

V_{GE(th)}

ICES

Cies

Coes

Cres

 Q_{G}

R_{Gint}

t_{d(on)}

tr

tf

Eoff

R_{th(j-s)}

 $R_{th(j-s)}$

 E_{on}

t_{d(off)}



MiniSKiiP[®] 2

IGBT module

SKiiP 24ACC12T4V1

Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532

Typical Applications*

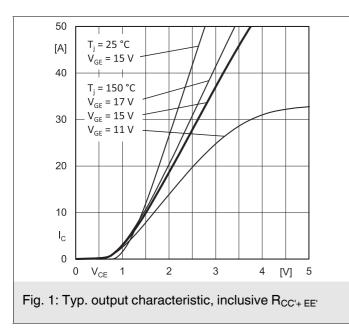
• 4Q inverters

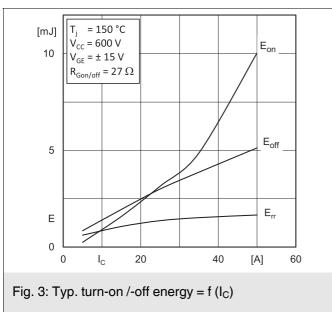
Remarks

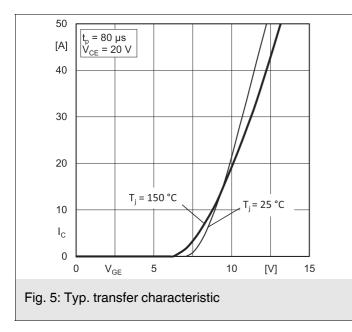
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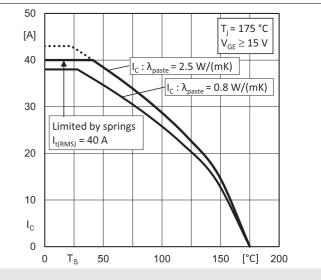
ACC			

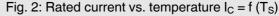
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 25 A	T _j = 25 °C		2.41	2.74	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.45	2.79	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		44	50	mΩ
		T _j = 150 °C		62	68	mΩ
I _{RRM}	$-1V_{GF} = +15/-15V$	T _j = 150 °C		23		Α
Q _{rr}		T _j = 150 °C		3.8		μC
E _{rr}		T _j = 150 °C		1.4		mJ
R _{th(j-s)}	per Diode, λ_{paste} =0.8 W/(mK)			1.6		K/W
R _{th(j-s)}	per Diode, λ_{paste} =2.5 W/(mK)			1.37		K/W
Module	·					
L _{CE}				-		nH
Ms	to heat sink		2		2.5	Nm
w				55		g
Temperat	ure Sensor	<u>.</u>				
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω
R(T)	$R_{(T)}$ =1000Ω[1+A(T-25°C)+B(T-25°C) ²] , A = 7.635*10 ⁻³ C ⁻¹ , B = 1.731*10 ⁻⁵ C ⁻²					

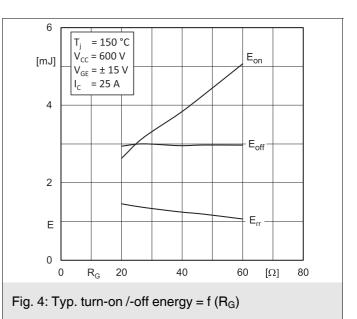


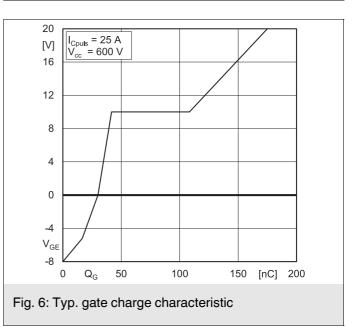


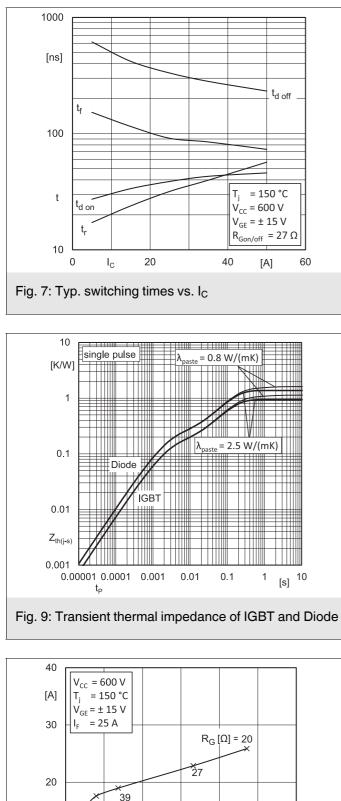


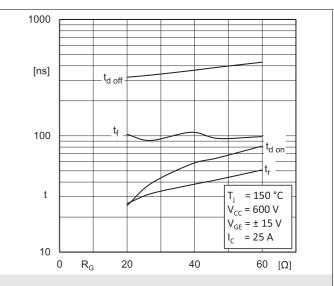


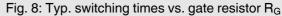


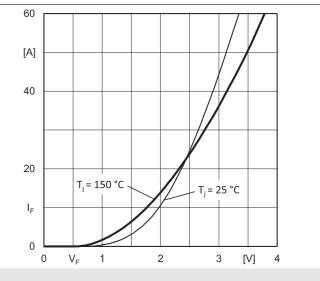


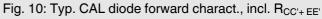


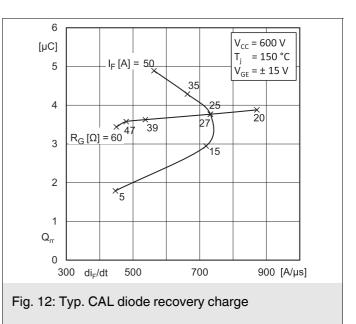


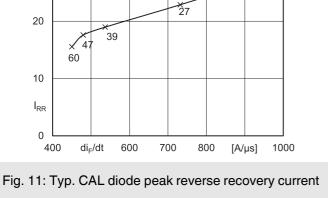


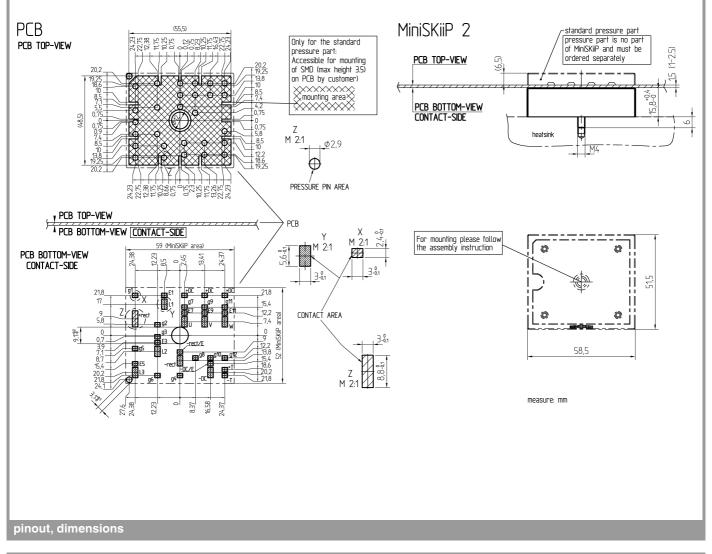


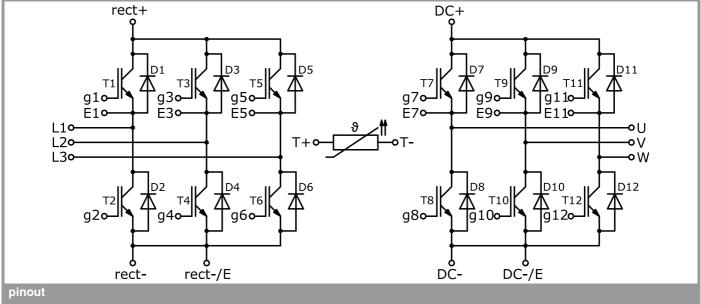












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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